

PJT138L

60V N-Channel Enhancement Mode MOSFET

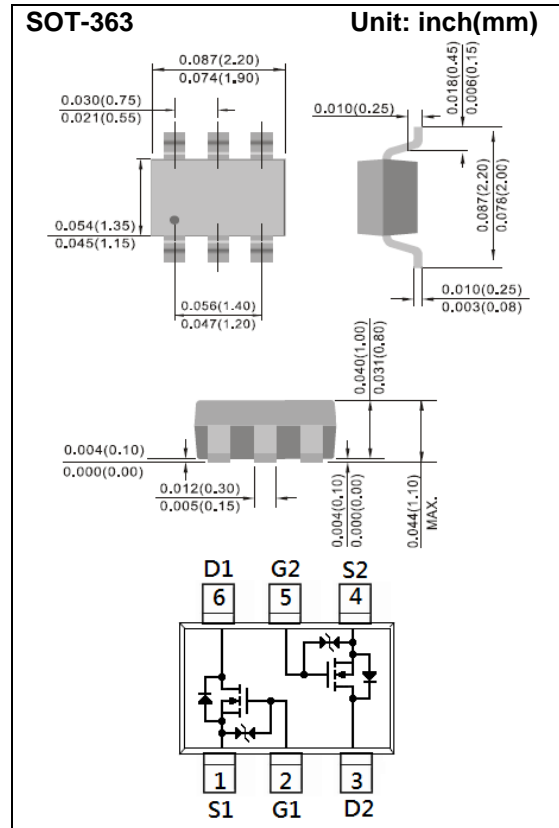
Voltage **60 V** **Current** **200mA**

Features

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@200mA < 4.2\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_D@100mA < 5\Omega$
- $R_{DS(ON)}$, $V_{GS}@2.5V$, $I_D@50mA < 7\Omega$
- Advanced Trench Process Technology
- ESD Protected
- Specially Designed for Relay driver, Speed line drive, etc.
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case : SOT-363 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0002 ounces, 0.006 grams
- Marking: T8L



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNIT	
Drain-Source Voltage	V_{DS}	60	V	
Gate-Source Voltage	V_{GS}	± 20	V	
Continuous Drain Current	I_D	200	mA	
Pulsed Drain Current	I_{DM}	1000	mA	
Power Dissipation	P_D	$T_A=25^\circ\text{C}$	350	mW
		Derate above 25°C	2.8	mW/ $^\circ\text{C}$
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55~150	$^\circ\text{C}$	
Typical Thermal resistance	$R_{\theta JA}$	357	$^\circ\text{C}/\text{W}$	
- Junction to Ambient (Note 3)				

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Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	60	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250uA	0.8	1.2	1.5	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =200mA	-	2.5	4.2	Ω
		V _{GS} =4.5V, I _D =100mA	-	2.8	5	
		V _{GS} =2.5V, I _D =50mA	-	3.7	7	
		V _{GS} =1.8V, I _D =10mA	-	12	-	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V	-	0.01	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	±1.0	±10	uA
Dynamic (Note 4)						
Total Gate Charge	Q _g	V _{DS} =15V, I _D =200mA, V _{GS} =4.5V (Note 1,2)	-	0.7	-	nC
Gate-Source Charge	Q _{gs}		-	0.33	-	
Gate-Drain Charge	Q _{gd}		-	0.2	-	
Input Capacitance	C _{iss}	V _{DS} =15V, V _{GS} =0V, f=1.0MHZ	-	15	-	pF
Output Capacitance	C _{oss}		-	8.4	-	
Reverse Transfer Capacitance	C _{rss}		-	4.2	-	
Turn-On Delay Time	t _{d(on)}	V _{DD} =10V, I _D =200mA, V _{GS} =10V, R _G =6Ω (Note 1,2)	-	7	-	ns
Turn-On Rise Time	t _r		-	22	-	
Turn-Off Delay Time	t _{d(off)}		-	21	-	
Turn-Off Fall Time	t _f		-	25	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I _S	---	-	-	200	mA
Diode Forward Voltage	V _{SD}	I _S =200mA, V _{GS} =0V	-	0.8	1.1	V

NOTES :

1. Pulse width ≤ 300us, Duty cycle ≤ 2%.
2. Essentially independent of operating temperature typical characteristics.
3. R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. mounted on a 1 inch square pad of copper.
4. Guaranteed by design, not subject to production testing.

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TYPICAL CHARACTERISTIC CURVES

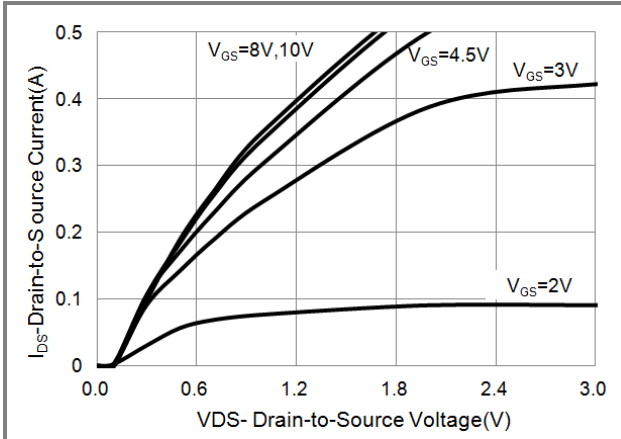


Fig.1 On-Region Characteristics

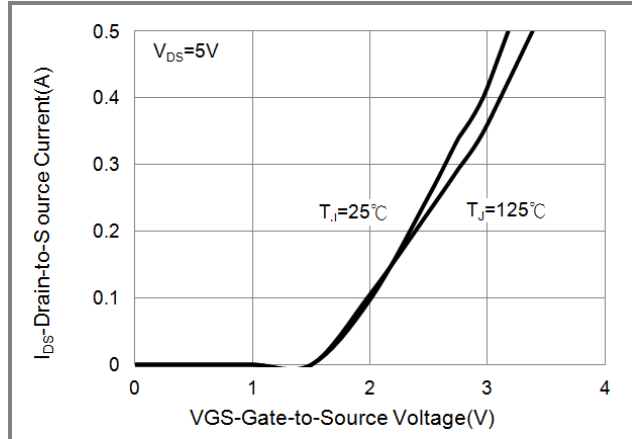


Fig.2 Transfer Characteristics

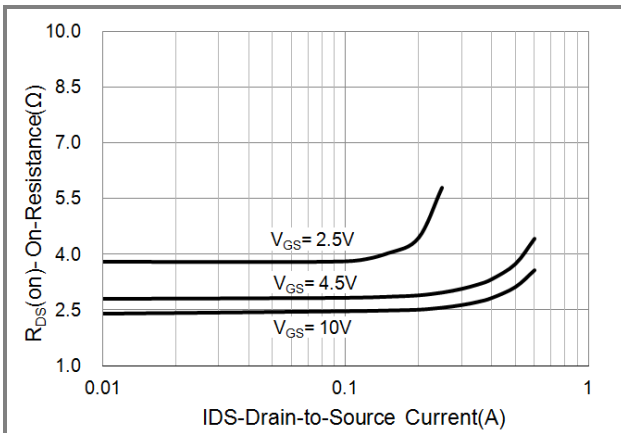


Fig.3 On-Resistance vs. Drain Current

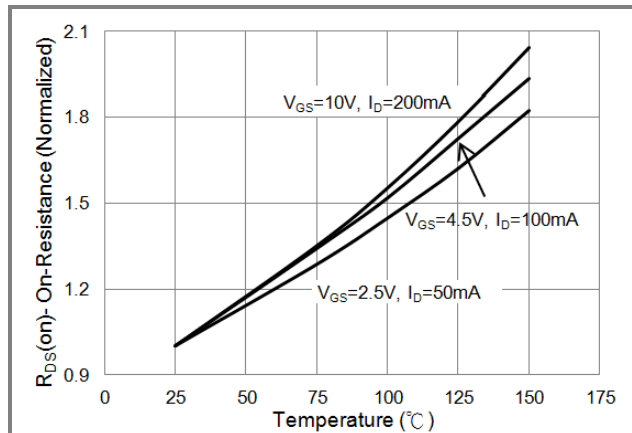


Fig.4 On-Resistance vs. Junction temperature

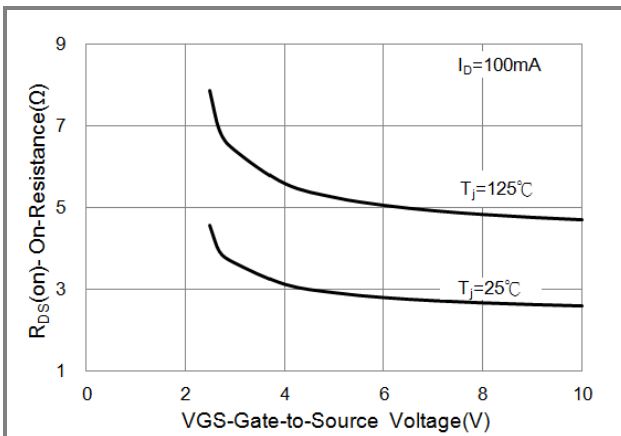


Fig.5 On-Resistance Variation with VGS.

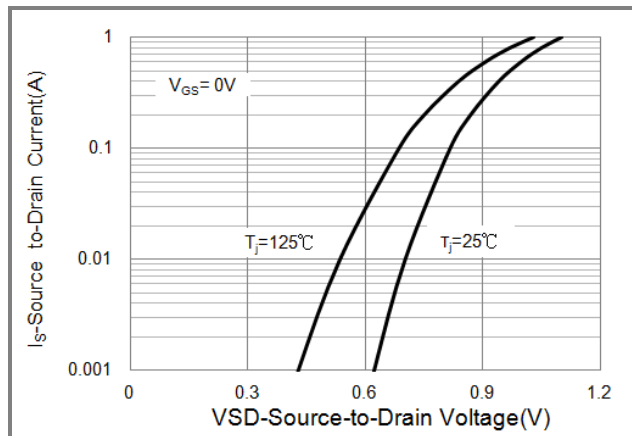


Fig.6 Body Diode Characteristics

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TYPICAL CHARACTERISTIC CURVES

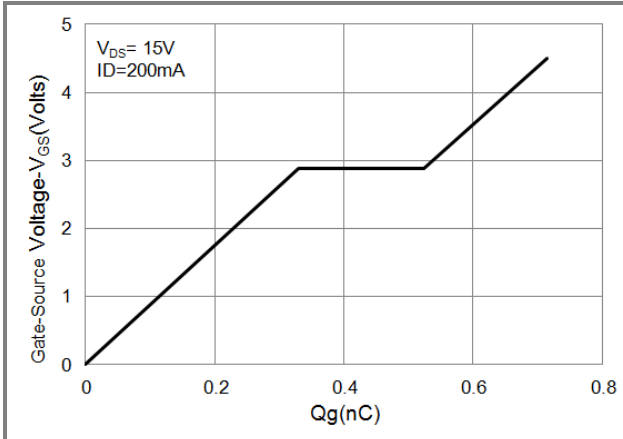


Fig.7 Gate-Charge Characteristics

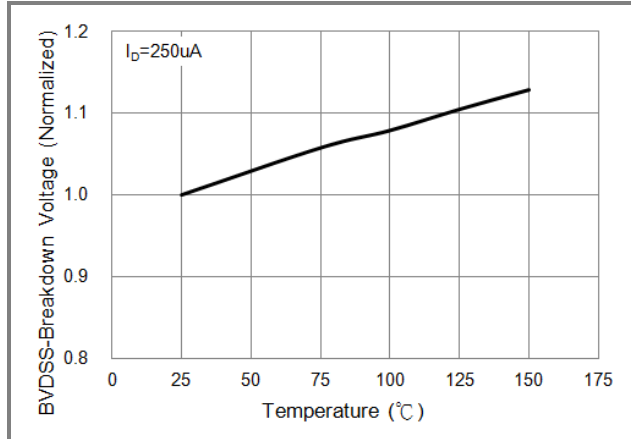


Fig.8 Breakdown Voltage Variation vs. Temperature

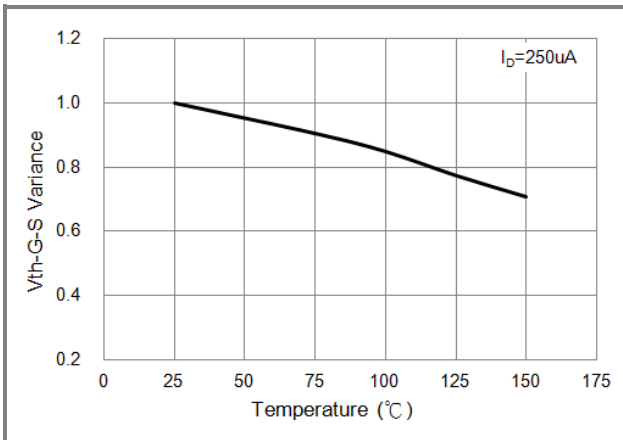


Fig.9 Threshold Voltage Variation with Temperature.

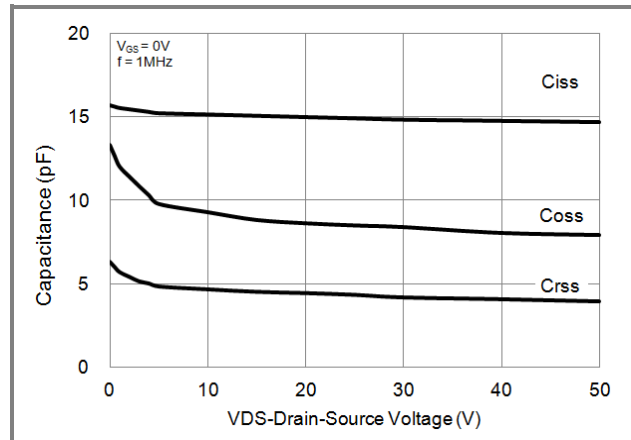


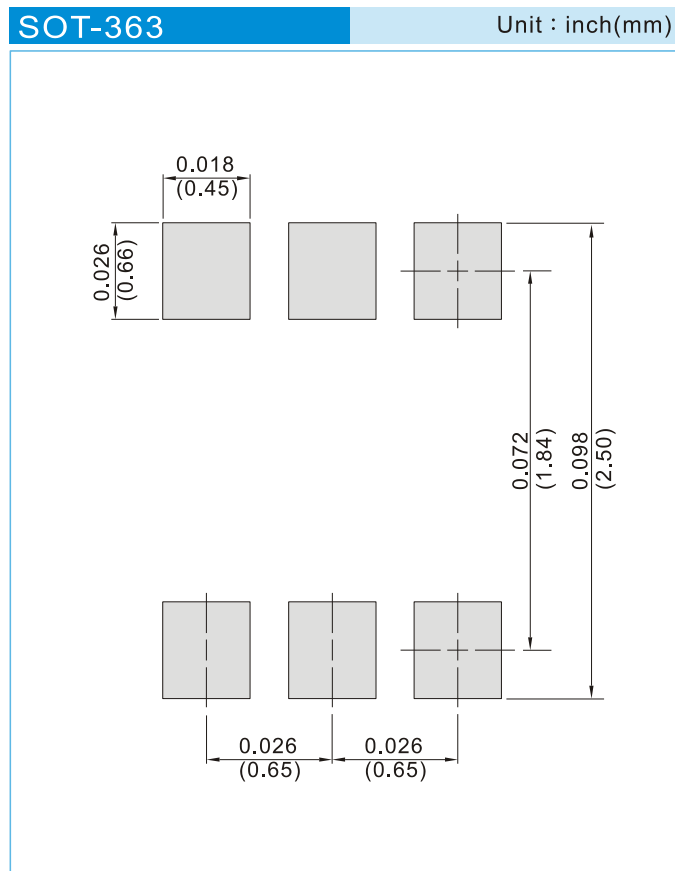
Fig.10 Capacitance vs. Drain-Source Voltage.

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Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJT138L	SOT-363	3K pcs / 7" reel	T8L
PJT138L	SOT-363	10K pcs / 13" reel	T8L

Mounting Pad Layout



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